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DATA SHEET**SCH2819**

MOSFET : N-Channel Silicon MOSFET

SBD : Schottky Barrier Diode

General-Purpose Switching Device
Applications**Features**

- Composite type with a N-Channel Silicon MOSFET (SCH1419) and a Schottky Barrier Diode (SS0503) contained in one package facilitating high-density mounting.
- [MOSFET]
 - Low ON-resistance.
 - Ultrahigh-speed switching.
 - 2.5V drive.
- [SBD]
 - Short reverse recovery time.
 - Low forward voltage.

Specifications**Absolute Maximum Ratings** at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
[MOSFET]				
Drain-to-Source Voltage	V _{DSS}		30	V
Gate-to-Source Voltage	V _{GS}		±12	V
Drain Current (DC)	I _D		1.5	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycles≤1%	6	A
Allowable Power Dissipation	P _D	Mounted on a ceramic board (900mm ² ×0.8mm) 1unit	0.6	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +125	°C
[SBD]				
Repetitive Peak Reverse Voltage	V _{RRM}		30	V
Nonrepetitive Peak Reverse Surge Voltage	V _{RSM}		30	V
Average Output Current	I _O		0.5	A
Surge Forward Current	I _{FSM}	50Hz sine wave, 1 cycle	3	A
Junction Temperature	T _J		-55 to +125	°C
Storage Temperature	T _{stg}		-55 to +125	°C

Marking : QU

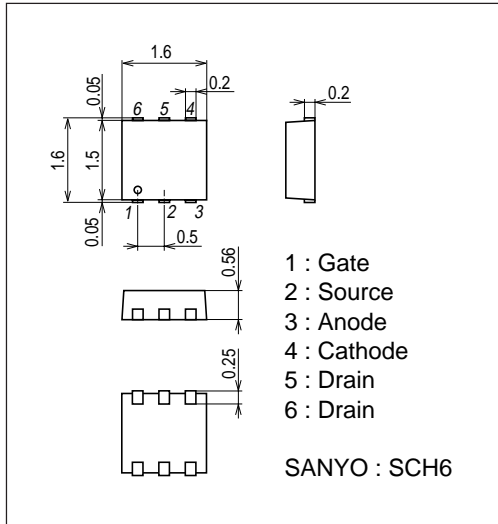
SCH2819

Electrical Characteristics at Ta=25°C

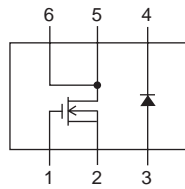
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[MOSFET]						
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1mA, V_{GS}=0V$	30			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V, V_{GS}=0V$			1	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 8V, V_{DS}=0V$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V, I_D=1mA$	0.4		1.3	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V, I_D=800mA$	1.3	2.2		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=800mA, V_{GS}=4V$		165	215	m Ω
	$R_{DS(on)2}$	$I_D=400mA, V_{GS}=2.5V$		210	295	m Ω
Input Capacitance	C_{iss}	$V_{DS}=10V, f=1MHz$		130		pF
Output Capacitance	C_{oss}	$V_{DS}=10V, f=1MHz$		22		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS}=10V, f=1MHz$		16		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit.		9		ns
Rise Time	t_r	See specified Test Circuit.		20		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit.		23		ns
Fall Time	t_f	See specified Test Circuit.		29		ns
Total Gate Charge	Q_g	$V_{DS}=10V, V_{GS}=4V, I_D=1.5A$		2.2		nC
Gate-to-Source Charge	Q_{gs}	$V_{DS}=10V, V_{GS}=4V, I_D=1.5A$		0.52		nC
Gate-to-Drain "Miller" Charge	Q_{gd}	$V_{DS}=10V, V_{GS}=4V, I_D=1.5A$		0.52		nC
Diode Forward Voltage	V_{SD}	$I_S=1.5A, V_{GS}=0V$		0.9	1.2	V
[SBD]						
Reverse Voltage	V_R	$I_R=0.5mA$	30			V
Forward Voltage	V_F	$I_F=0.5A$		0.42	0.48	V
Reverse Current	I_R	$V_R=15V$			120	μA
Interterminal Capacitance	C	$V_R=10V, f=1MHz$		13		pF
Reverse Recovery Time	t_{rr}	$I_F=I_R=100mA$, See specified Test Circuit.			10	ns

Package Dimensions

unit : mm
7028-003



Electrical Connection



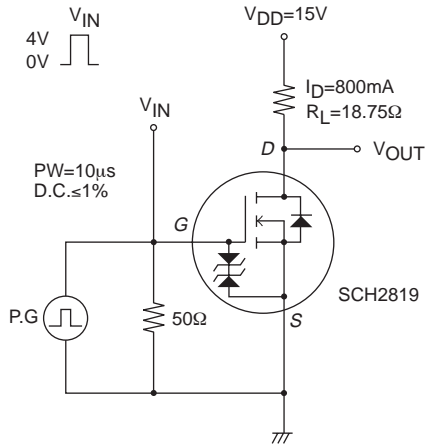
1 : Gate
2 : Source
3 : Anode
4 : Cathode
5 : Drain
6 : Drain

Top view

SCH2819

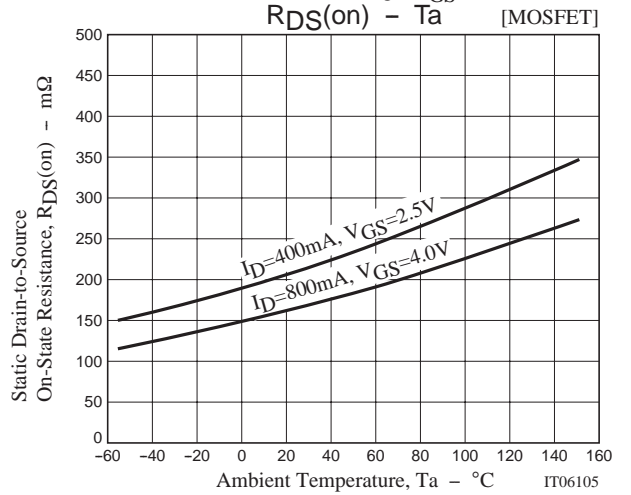
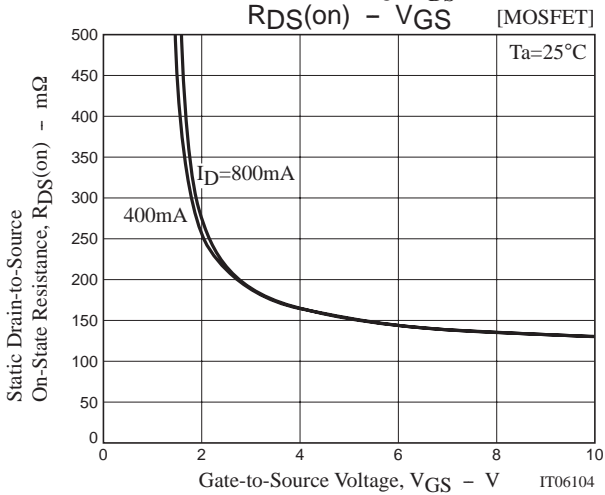
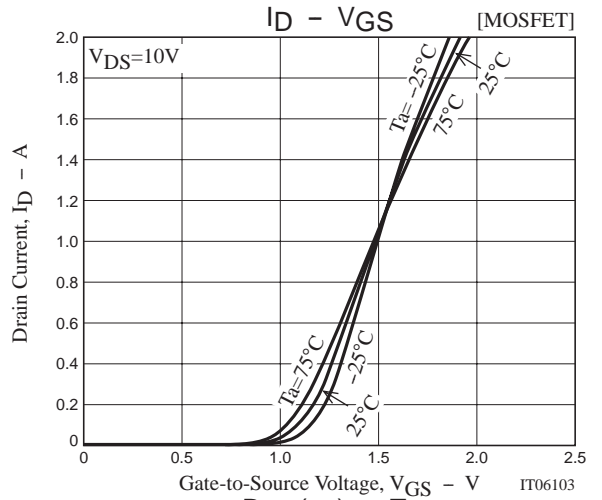
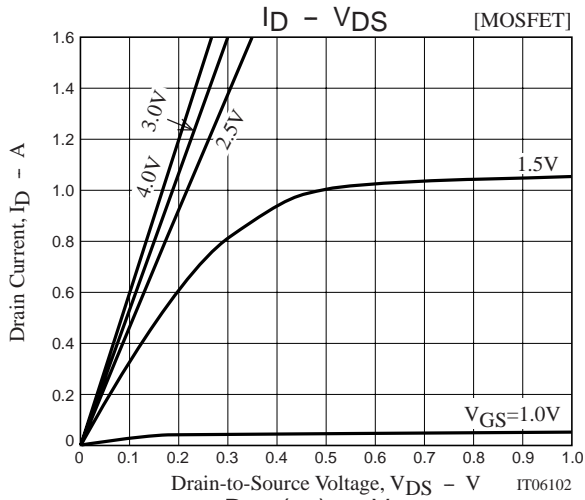
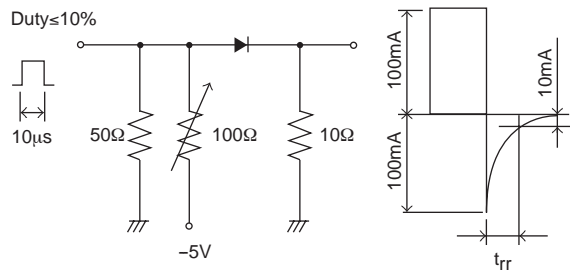
Switching Time Test Circuit

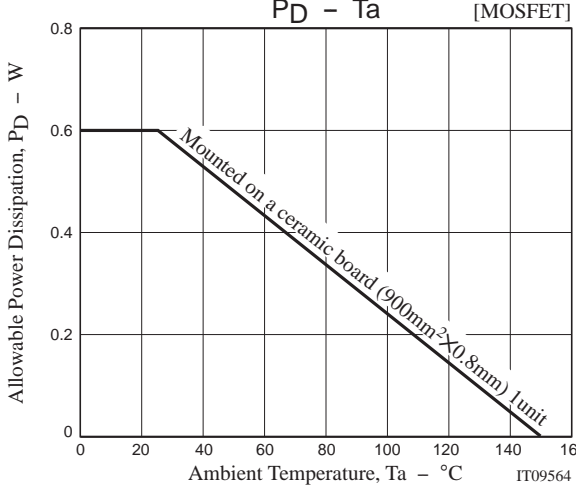
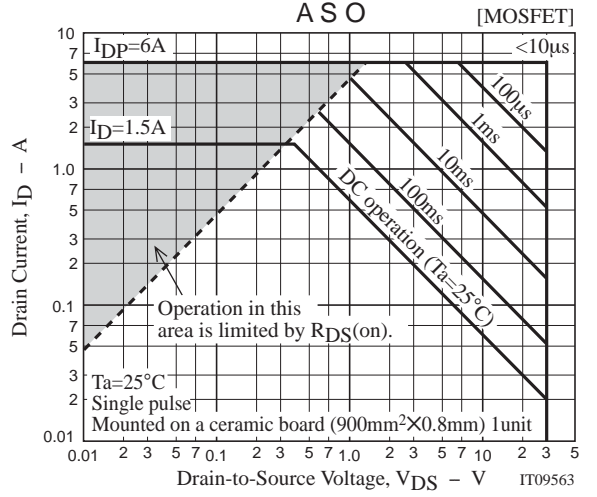
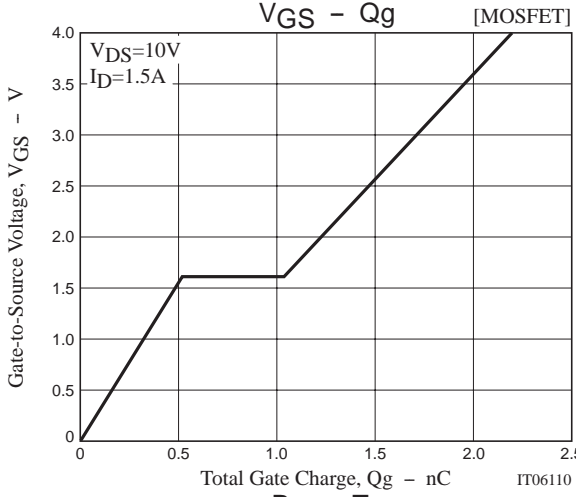
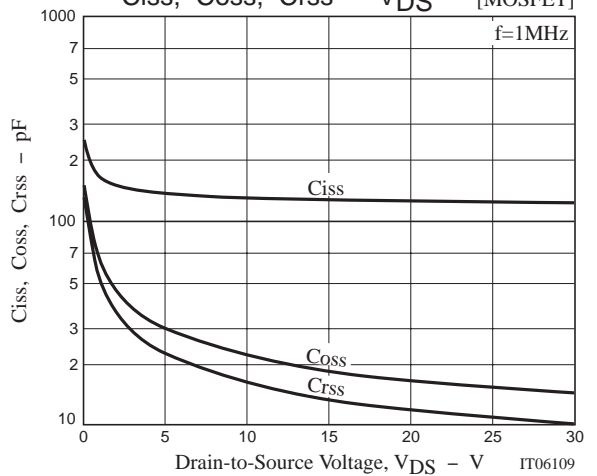
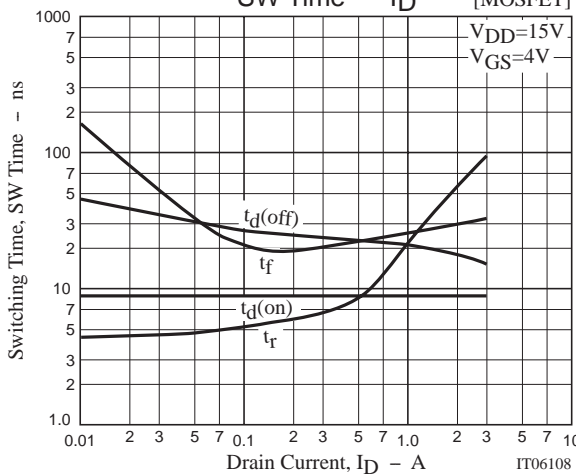
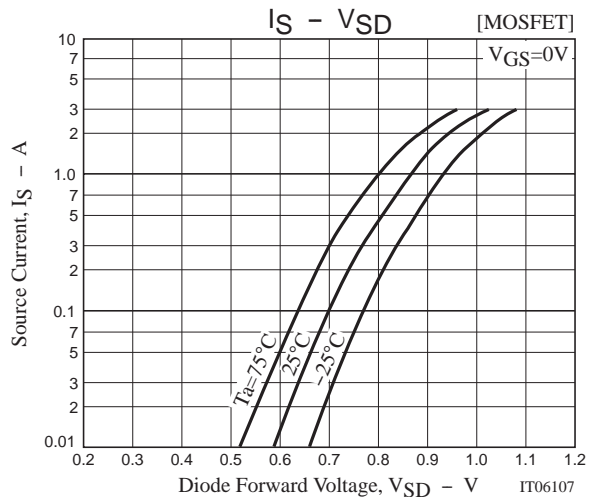
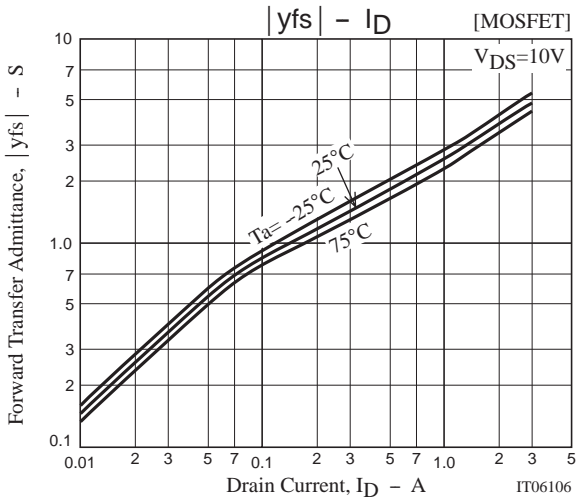
[MOSFET]

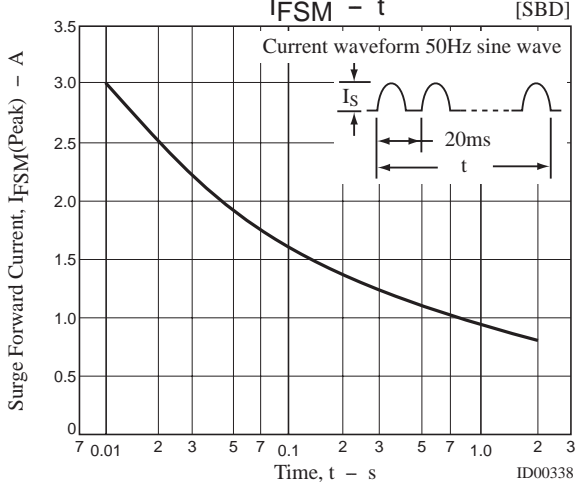
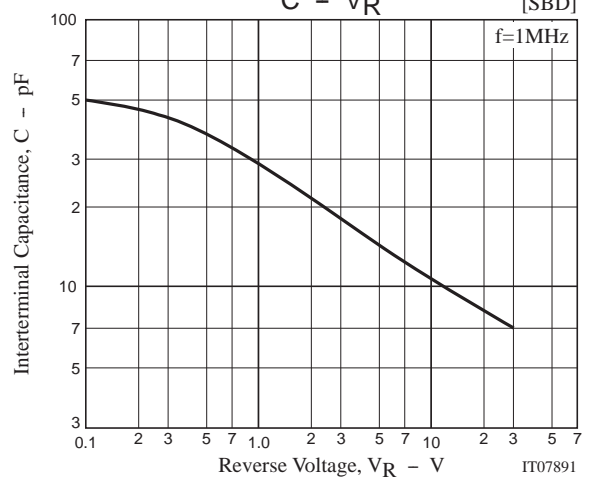
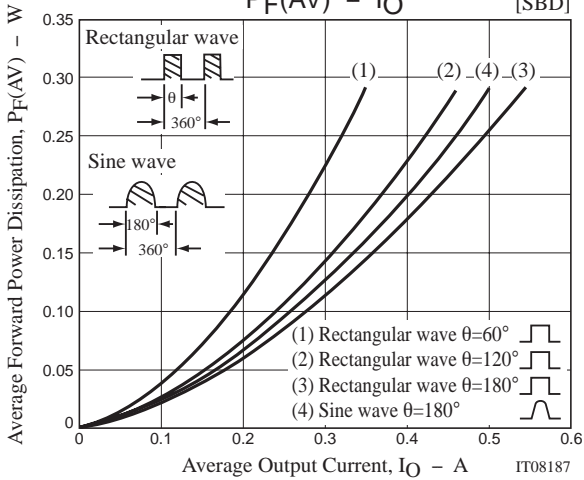
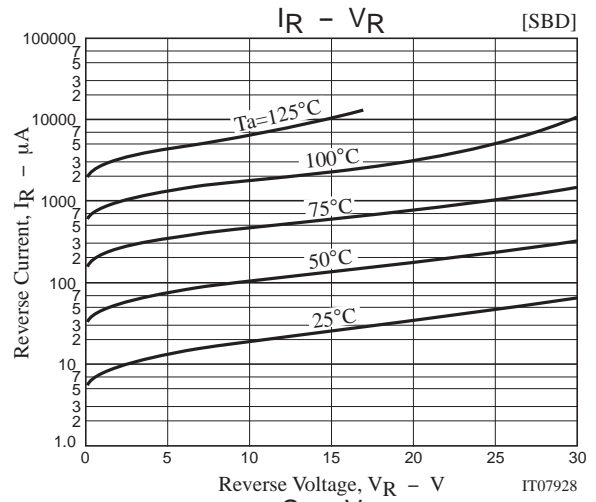
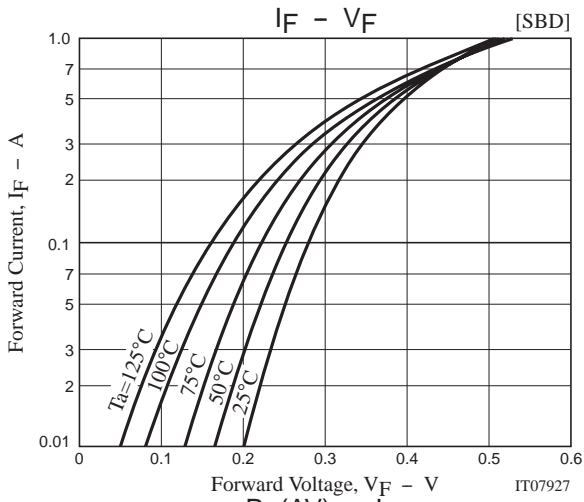


t_{rr} Test Circuit

[SBD]







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